

APTDF30H1201G

Fast Diode Full Bridge Power Module

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CR1

CF

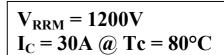
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Application

- Uninterruptible Power Supply (UPS)
- Induction heating
- Welding equipment
- High speed rectifiers

Features

- Ultra fast recovery times
- Soft recovery characteristics
- High blocking voltage
- High current
- Low leakage current
- Very low stray inductance
- High level of integration

Benefits

- Outstanding performance at high frequency operation
- Low losses
- Low noise switching
- Solderable terminals for easy PCB mounting
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- RoHS Compliant
- All multiple inputs and outputs must be shorted together 3/4; 5/6; 7/8; 1/2; 9/10

Absolute maximum ratings

Symbol	Parameter			Max ratings	Unit		
V _R	Maximum DC reverse Voltage				1200	V	
V _{RRM}	Maximum Peak Repetitive Revers	erse Voltage			1200	v	
I _{F(AV)}	Maximum Average Forward	Destru sevel	500/	$T_C = 25^{\circ}C$	43		
	Current	Duty cycl	e = 50%	$T_C = 80^{\circ}C$	30	А	
I _{FSM}	Non-Repetitive Forward Surge Cu	rrent 8.3ms		$T_J = 45^{\circ}C$	210		

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com

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All ratings (a) $T_j = 25^{\circ}C$ unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit		
$V_{\rm F}$		$I_F = 30A$			2.6	3.1		
	V _F	Diode Forward Voltage	$I_F = 60A$			3.2		V
		$I_F = 30A$	$T_{j} = 125^{\circ}C$		1.8			
I _{RM}	Maximum Reverse Leakage Current	$V_{\rm R} = 1200 V$ $T_{\rm i} = 25^{\circ} C$	$T_i = 25^{\circ}C$			100	۸	
	I _{RM} Iviaxii	Waximum Reverse Leakage Current	$V_{\rm R} = 1200 V$ $T_{\rm j} =$	$T_{j} = 125^{\circ}C$			500	μA
CT	Junction Capacitance	$V_R = 200V$			36		pF	

Dynamic Characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
t _{rr}	Reverse Recovery Time		$T_j = 25^{\circ}C$		300		ns
۲r	Reverse Recovery Time		$T_{j} = 125^{\circ}C$		380		115
Q _{rr}	Reverse Recovery Charge	$I_F = 30A$ $V_R = 800V$	$T_j = 25^{\circ}C$		360		nC
Чп	Reverse Receivery charge	$di/dt = 200 A/\mu s$	$T_{i} = 125^{\circ}C$		1700		пе
I _{RRM}	Reverse Recovery Current		$T_j = 25^{\circ}C$		4		А
IRRM			$T_{j} = 125^{\circ}C$		8		11
t _{rr}	Reverse Recovery Time	$I_{\rm F} = 30A$ $V_{\rm R} = 800V$ di/dt=1000A/µs			160		ns
Q _{rr}	Reverse Recovery Charge		$T_j = 125^{\circ}C$		2550		nC
I _{RRM}	Reverse Recovery Current				28		А

Thermal and package characteristics

Symbol	Characteristic			Min	Тур	Max	Unit
R_{thJC}	Junction to Case Thermal Resistance					1.2	°C/W
V _{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
TJ	Operating junction temperature range			-40		175	
T _{STG}	Storage Temperature Range			-40		125	°C
T _C	Operating Case Temperature			-40		100	
Torque	Mounting torque	To heatsink	M4	2		3	N.m
Wt	Package Weight					80	g

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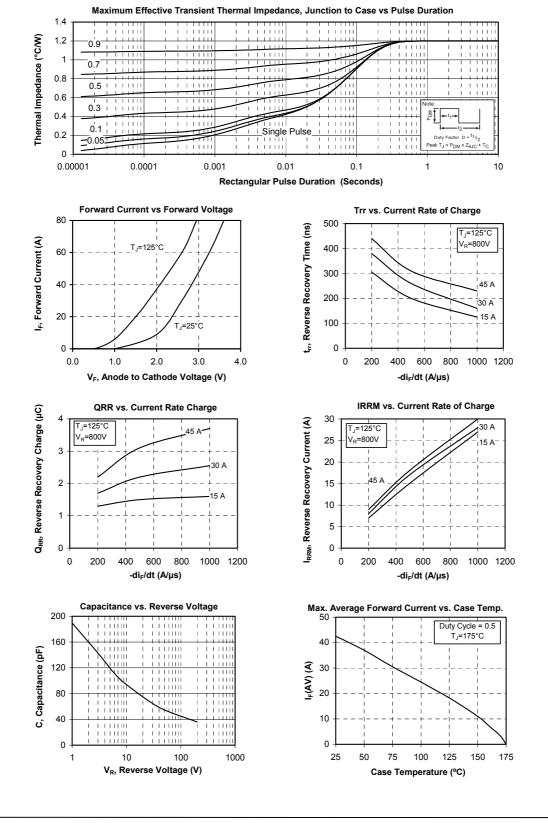
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Typical Performance Curve



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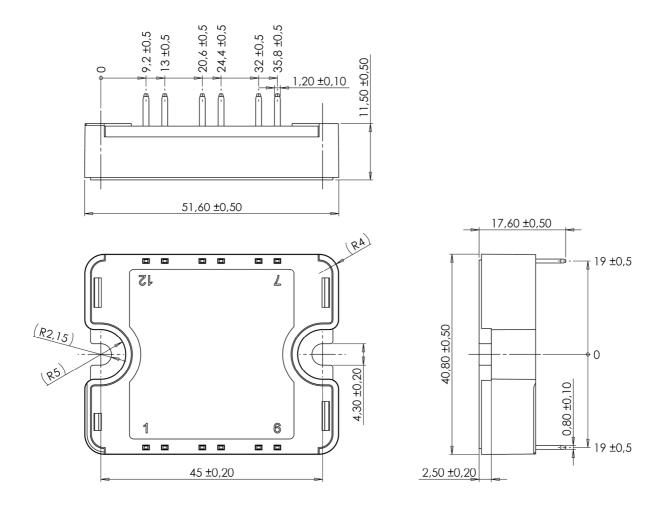
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SP1 Package outline (dimensions in mm)



See application note 1904 - Mounting Instructions for SP1 Power Modules on www.microsemi.com

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